1N1183(R) THRU 1N3768(R)

STANDARD RECOVERY DIODE STUD TYPES 35A

Features

High Surge Capability
Types up to 1000V V_{RRM}

Maximum Ratings

Junction Operating Temperature : -55 $^{\circ}\text{C}$ to+175 $^{\circ}\text{C}$

Storage Temperature : -55 °C to+175 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
1N1183(R)	50 V	35 V	50 V
1N1184(R)	100 V	70 V	100 V
1N1186(R)	200 V	140 V	200 V
1N1188(R)	400 V	280 V	400 V
1N1189(R)	500 V	350 V	500 V
1N1190(R)	600 V	420 V	600 V
1N3765(R)	700 V	490 V	700 V
1N3766(R)	800 V	560 V	800 V
1N3767(R)	900 V	630 V	900 V
1N3768(R)	1000 V	700 V	1000 V

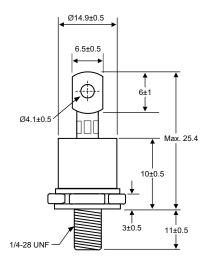
Electrical Characteristics @ 25 $^{\circ}$ C Unless Otherwise Specified

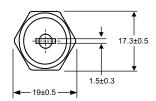
Average Forward Current (Per pkg)	lf(AV)	35A	Tc = 150°C
Peak Forward ^{1N1183(R)-1N1190(R)} Surge _{1N3765(R)-1N3768(R)} Current	lfsm	595A 475A	8.3ms , half sine
Maximum Instantaneous Forward Voltage*	VF	1.1V	I _{FM} =35A; Т _J = 25°С
Maximum Instantaneous Reverse Current At Rated DC Blockig Voltage*	lr	10μA 12mA	T _J = 25°C T _J = 175°C
Maximum Thermal Resistance Junction To Case	R ₀ jc	1.18°C/W	
Mounting torque	Inch pounds (in-pb)	30	

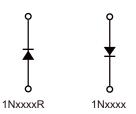
^{*}Pulse Test: Pulse Width 300 µsec, Duty Cycle < 2%



Dimensions in mm (1 mm = 0.0394")

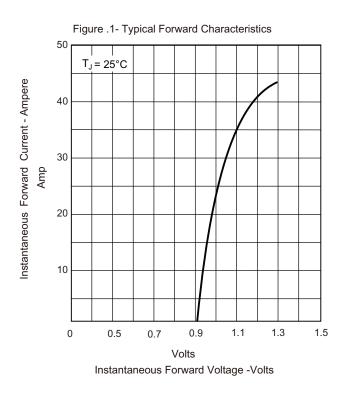


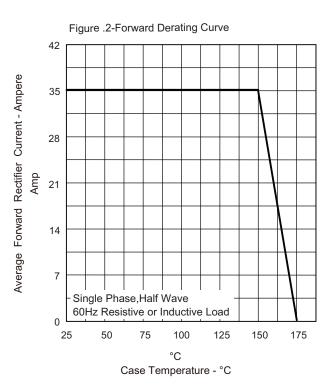


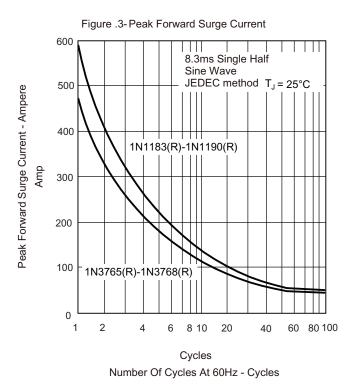


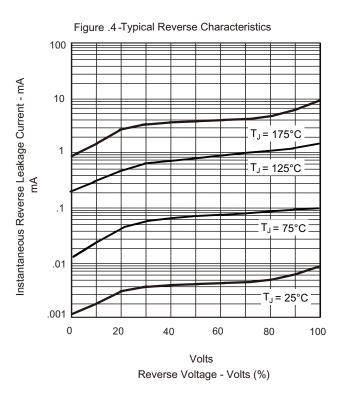
Marking Notes:

- 1. R= Stud Reverse Polarity : Anode to Stud
- 2. None = Stud normal Polarity: Cathode to Stud











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